

# 2SC1906

Silicon NPN Epitaxial Planar

# HITACHI

ADE-208-1058 (Z)

1st. Edition

Mar. 2001

## Application

- VHF amplifier
- Mixer, Local oscillator

勝特力材料 886-3-5753170

勝特力电子(上海) 86-21-54151736

勝特力电子(深圳) 86-755-83298787

[Http://www.100y.com.tw](http://www.100y.com.tw)

## Outline

TO-92 (2)



1. Emitter
2. Collector
3. Base

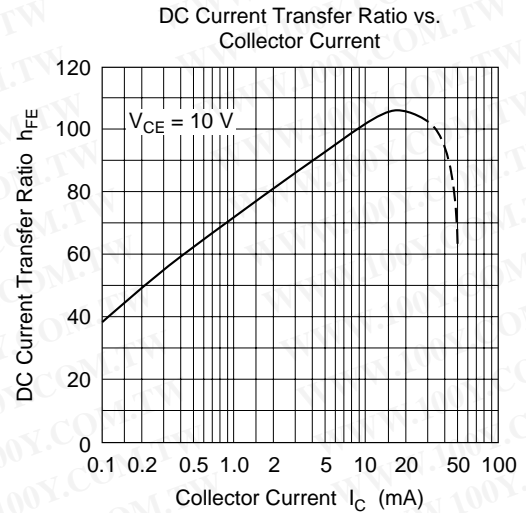
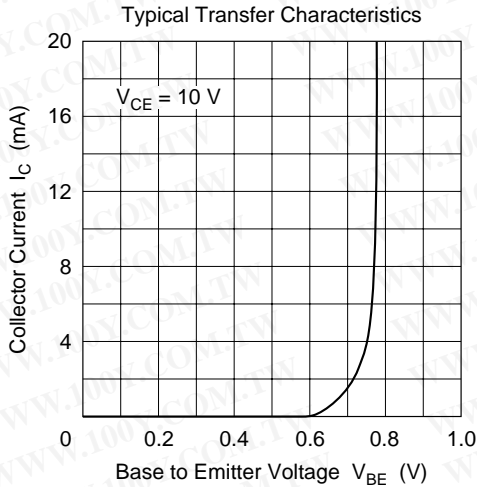
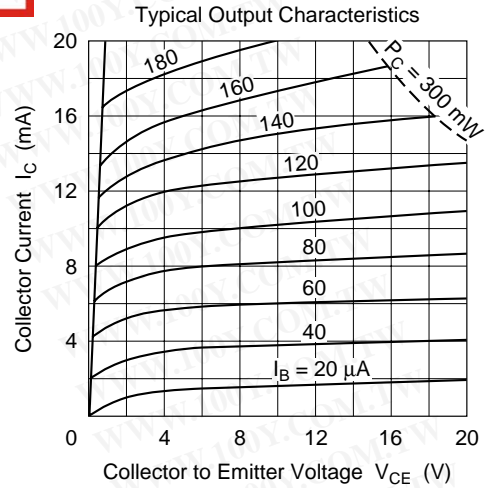
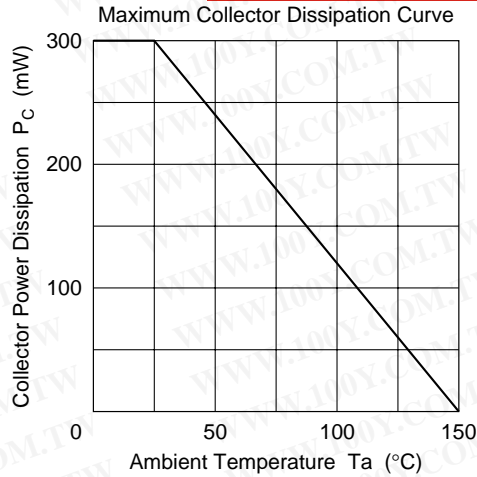
## Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings	Unit
Collector to base voltage	$V_{CBO}$	30	V
Collector to emitter voltage	$V_{CEO}$	19	V
Emitter to base voltage	$V_{EBO}$	2	V
Collector current	$I_C$	50	mA
Emitter current	$I_E$	-50	mA
Collector power dissipation	$P_C$	300	mW
Junction temperature	$T_J$	150	°C
Storage temperature	$T_{stg}$	-55 to +150	°C

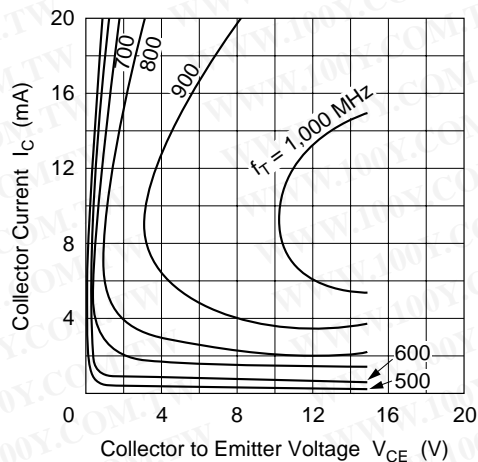
## Electrical Characteristics (Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	30	—	—	V	$I_C = 10 \mu A, I_E = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	19	—	—	V	$I_C = 3 \text{ mA}, R_{BE} = \infty$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	2	—	—	V	$I_E = 10 \mu A, I_C = 0$
Collector cutoff current	$I_{CBO}$	—	—	0.5	$\mu A$	$V_{CB} = 10 \text{ V}, I_E = 0$
DC current transfer ratio	$h_{FE}$	40	—	—		$V_{CE} = 10 \text{ V}, I_C = 10 \text{ mA}$
Gain bandwidth product	$f_T$	600	1000	—	MHz	$V_{CE} = 10 \text{ V}, I_C = 10 \text{ mA}$
Collector output capacitance	$C_{ob}$	—	1.0	2.0	pF	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$
Collector to emitter saturation voltage	$V_{CE(sat)}$	—	0.2	1.0	V	$I_C = 20 \text{ mA}, I_B = 4 \text{ mA}$
Base time constant	$r_{bb'} \cdot C_C$	—	10	25	ps	$V_{CB} = 10 \text{ V}, I_C = 10 \text{ mA}, f = 31.8 \text{ MHz}$
Power gain	PG	—	33	—	dB	$V_{CE} = 10 \text{ V}, I_C = 5 \text{ mA}, f = 45 \text{ MHz}$
		—	18	—	dB	$V_{CE} = 10 \text{ V}, I_C = 5 \text{ mA}, f = 200 \text{ MHz}$

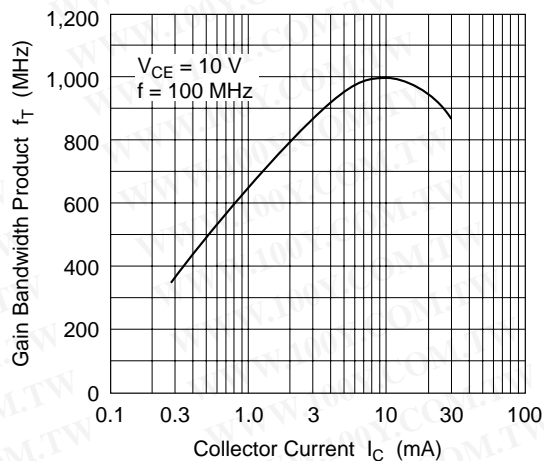
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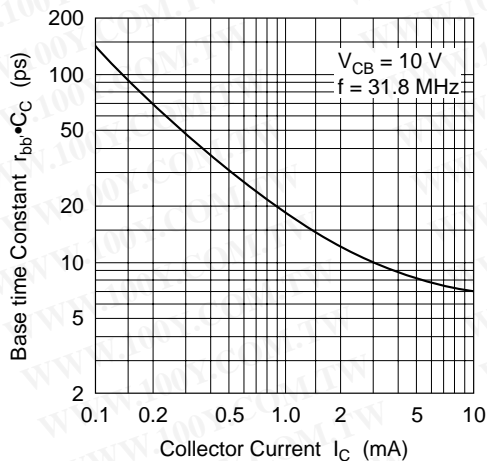
Gain Bandwidth Product Curve



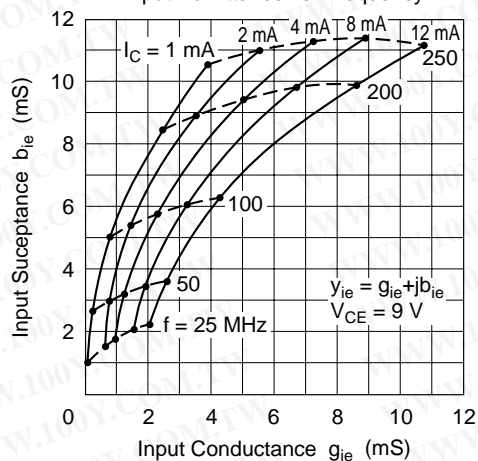
Gain Bandwidth Product vs. Collector Current



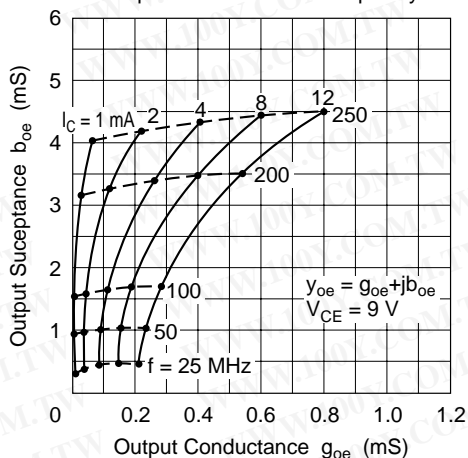
Base Time Constant vs. Collector Current



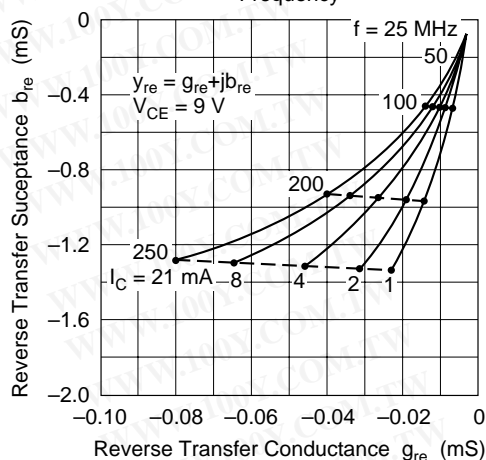
Input Admittance vs. Frequency



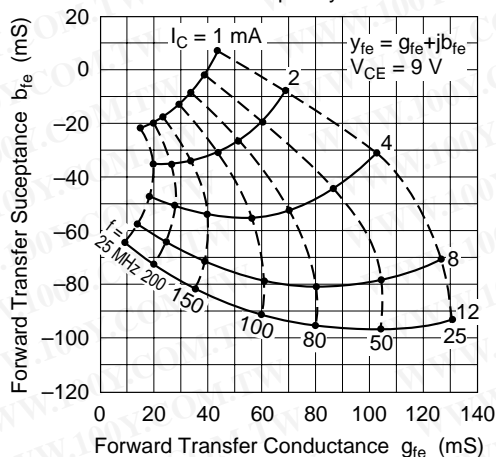
Output Admittance vs. Frequency



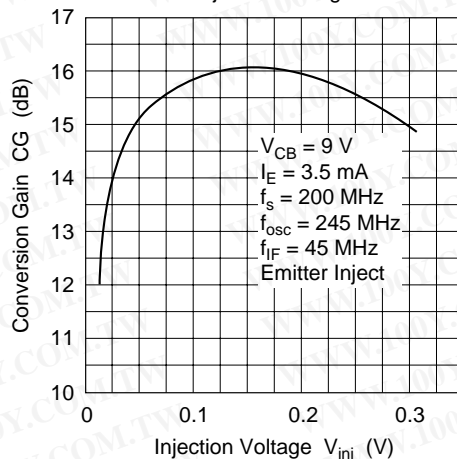
Reverse Transfer Admittance vs. Frequency



Forward Transfer Admittance vs. Frequency

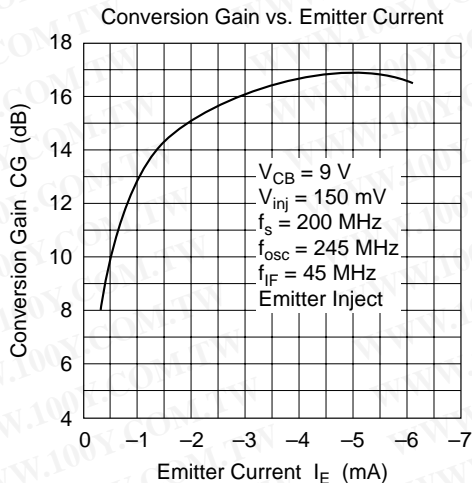


Conversion Gain vs. Local Oscillating Injection Voltage



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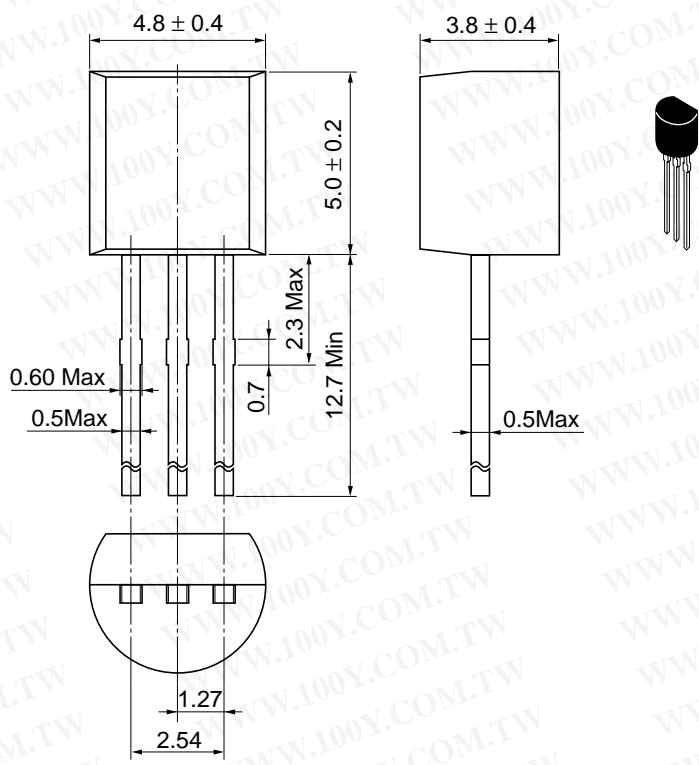


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Package Dimensions

As of January, 2001  
Unit: mm



Hitachi Code	TO-92 (2)
JEDEC	Conforms
EIAJ	Conforms
Mass (reference value)	0.25 g

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